

BFR540 NPN 9 GHz wideband transistor Rev. 6 — 13 September 2011

**Product data sheet** 

## 1. Product profile

#### 1.1 General description

The BFR540 is an NPN silicon planar epitaxial transistor in a SOT23 plastic package.

#### 1.2 Features and benefits

- High power gain
- Low noise figure
- High transition frequency
- Gold metallization ensures excellent reliability.

#### **1.3 Applications**

- RF front end wideband applications in the GHz range
  - Analog and digital cellular telephones
  - Cordless telephones (CT1, CT2, DECT, etc.)
  - Radar detectors
  - Satellite TV tuners (SATV)
  - MATV/CATV amplifiers
  - Repeater amplifiers in fiber-optic systems.

#### 1.4 Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	-	20	V
$V_{CES}$	collector-emitter voltage	$R_{BE} = 0 \ \Omega$	-	-	15	V
I <sub>C</sub>	collector current (DC)		-	-	120	mA
P <sub>tot</sub>	total power dissipation	$T_{sp} \le 70 \ ^{\circ}C$	<u>[1]</u> -	-	500	mW
h <sub>FE</sub>	DC current gain	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}$	100	120	250	
C <sub>re</sub>	feedback capacitance	$    I_C = i_c = 0 \text{ A}; V_{CB} = 8 \text{ V};                                   $	-	0.6	-	pF
f <sub>T</sub>	transition frequency	I <sub>C</sub> = 40 mA; V <sub>CE</sub> = 8 V; f = 1 GHz	-	9	-	GHz
G <sub>UM</sub>	maximum unilateral power gain	$\label{eq:lc} \begin{array}{l} I_C = 40 \text{ mA};  V_{CE} = 8  \text{V}; \\ T_{amb} = 25 \ ^\circ\text{C} \end{array}$				
		f = 900 MHz	-	14	-	dB
		f = 2 GHz	-	7	-	dB



Table 1.	Quick reference data	continued				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
s <sub>21</sub>   <sup>2</sup>	insertion power gain	$\label{eq:lc} \begin{array}{l} I_{C} = 40 \text{ mA}; \ V_{CE} = 8 \text{ V}; \\ T_{amb} = 25 \ ^{\circ}\text{C}; \\ f = 900 \text{ MHz} \end{array}$	12	13	-	dB
NF noise figure	$\Gamma_{s} = \Gamma_{opt}; V_{CE} = 8 V;$ $T_{amb} = 25 \text{ °C}$					
	I <sub>C</sub> = 10 mA; f = 900 MHz	-	1.3	1.8	dB	
	I <sub>C</sub> = 40 mA; f = 900 MHz	-	1.9	2.4	dB	
		I <sub>C</sub> = 10 mA; f = 2 GHz	-	2.1	-	dB

[1]  $T_{sp}$  is the temperature at the soldering point of the collector tab.

## 2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Symbol
1	base	_	
2	emitter		3
3	collector		

## 3. Ordering information

Table 3.         Ordering information					
Type numbe	r Package				
	Name	Description	Version		
BFR540	-	plastic surface mounted package; 3 leads	SOT23		

## 4. Marking

Table 4. Marking	
Type number	Marking code <sup>[1]</sup>
BFR540	33*

[1] \* = p: Made in Hong Kong

\* = t: Made in Malaysia

\* = W: Made in China.

sym021

## 5. Limiting values

Table 5. In accorda	Limiting values nce with the Absolute Maximut	m Rating System (IEC	C 60134).		
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	20	V
V <sub>CES</sub>	collector-emitter voltage	$R_{BE} = 0 \ \Omega$	-	15	V
$V_{\text{EBO}}$	emitter-base voltage	open collector	-	2.5	V
l <sub>C</sub>	collector current (DC)		-	120	mA
P <sub>tot</sub>	total power dissipation	$T_{sp} \le 70 \ ^{\circ}C$	<u>[1]</u> -	500	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	175	°C

[1]  $T_{sp}$  is the temperature at the soldering point of the collector tab.

## 6. Thermal characteristics

Table 6.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-sp)}$	thermal resistance from junction to soldering point		[1] 260	K/W
[1] T <sub>sp</sub> is	the temperature at the soldering point of the collector tab.			

## 7. Characteristics

# Table 7.Characteristics $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector cut-off current	$I_{E} = 0 \text{ A}; V_{CB} = 8 \text{ V}$		-	-	50	nA
h <sub>FE</sub>	DC current gain	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V}$		100	120	250	
C <sub>e</sub>	emitter capacitance	$\begin{split} I_C = i_c = 0 \text{ A};  V_{EB} = 0.5 \text{ V}; \\ f = 1 \text{ MHz} \end{split}$		-	2	-	pF
C <sub>c</sub>	collector capacitance	$  I_E = i_e = 0 \text{ A};  V_{CB} = 8 \text{ V}; $ $ f = 1 \text{ MHz} $		-	0.9	-	pF
C <sub>re</sub>	feedback capacitance	$I_{C} = 0 \text{ A}; V_{CB} = 8 \text{ V};$ f = 1 MHz		-	0.6	-	pF
f <sub>T</sub>	transition frequency	I <sub>C</sub> = 40 mA; V <sub>CE</sub> = 8 V; f = 1 GHz		-	9	-	GHz
G <sub>UM</sub>	maximum unilateral power	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V};$ $T_{amb} = 25 \text{ °C}$	[1]				
gain	gain	f = 900 MHz		-	14	-	dB
		f = 2 GHz		-	7	-	dB
$ s_{21} ^2$	insertion power gain	$I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V};$ $T_{amb} = 25 \text{ °C}; f = 900 \text{ MHz}$		12	13	-	dB

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
NF noise figur	noise figure	$\Gamma_{s} = \Gamma_{opt}; V_{CE} = 8 V;$ $T_{amb} = 25 \text{ °C}$				
		I <sub>C</sub> = 10 mA; f = 900 MHz	-	1.3	1.8	dB
		I <sub>C</sub> = 40 mA; f = 900 MHz	-	1.9	2.4	dB
		I <sub>C</sub> = 10 mA; f = 2 GHz	-	2.1	-	dB
P <sub>L(1dB)</sub>	output power at 1 dB gain compression	$    I_{C} = 40 \text{ mA}; V_{CE} = 8 \text{ V};     R_{L} = 50 \Omega; T_{amb} = 25 \text{ °C};     f = 900 \text{ MHz} $	-	21	-	dBm
ITO	third order intercept point		[2] _	34	-	dBm
Vo	output voltage	$\label{eq:lc} \begin{array}{l} I_{C} = 40 \text{ mA}; \ V_{CE} = 8 \text{ V}; \\ Z_{L} = Z_{S} = 75 \ \Omega; \\ T_{amb} = 25 \ ^{\circ}\text{C} \end{array}$	<u>[3]</u> _	550	-	mV

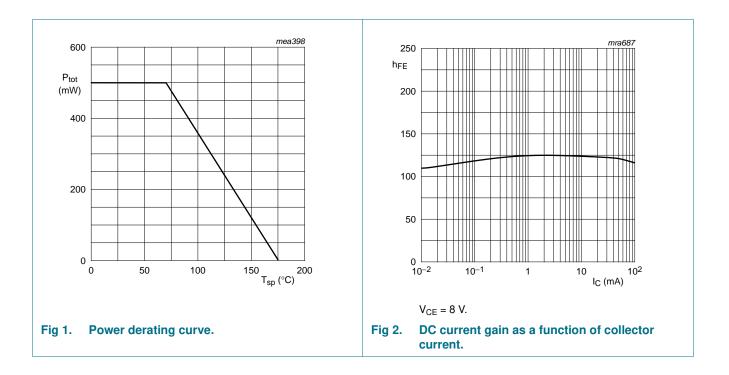
### Table 7. Characteristics ... continued T\_ = 25 °C unloss otherwise specified

[1]  $G_{UM}$  is the maximum unilateral power gain, assuming  $s_{12}$  is zero and

$$G_{UM} = 10 \log \frac{|s_{2I}|^2}{(1 - |s_{1I}|^2)(1 - |s_{22}|^2)} dB.$$

 $\label{eq:loss} \begin{array}{ll} \mbox{[2]} & I_C = 40 \mbox{ mA; } V_{CE} = 8 \mbox{ V; } R_L = 50 \ \Omega; \mbox{ } T_{amb} = 25 \ ^\circ C; \mbox{ } f = 900 \mbox{ MHz; } f_p = 900 \mbox{ MHz; } f_q = 902 \mbox{ MHz.} \\ \mbox{ Measured at } f_{(2p-q)} = 898 \mbox{ MHz and } f_{(2q-p)} = 904 \mbox{ MHz.} \end{array}$ 

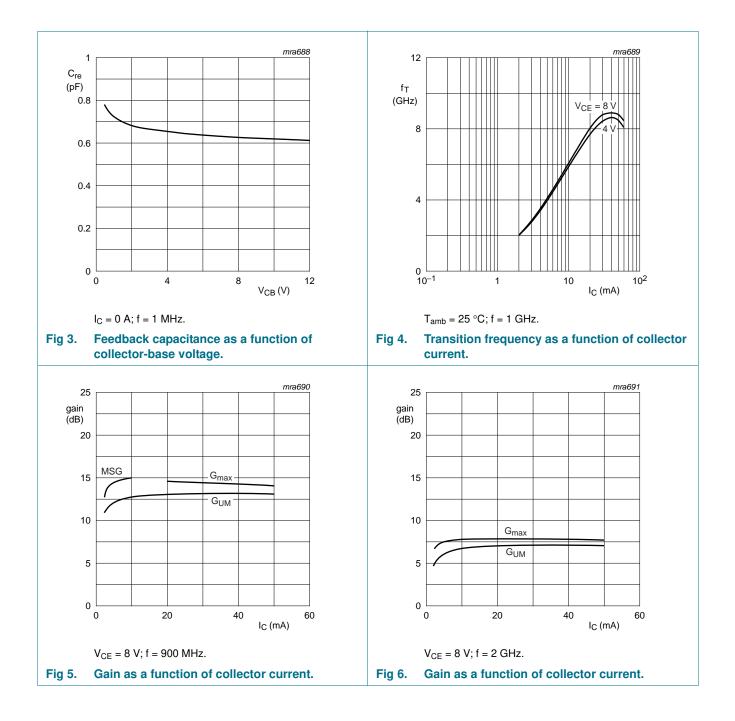
[3]  $d_{im} = -60 \text{ dB} \text{ (DIN 45004B)}; V_p = V_O; V_q = V_O - 6 \text{ dB}; f_p = 795.25 \text{ MHz}; V_R = V_O - 6 \text{ dB}; f_q = 803.25 \text{ MHz}; f_r = 805.25 \text{ MHz}.$ Measured at  $f_{(p+q-r)} = 793.25 \text{ MHz}.$ 



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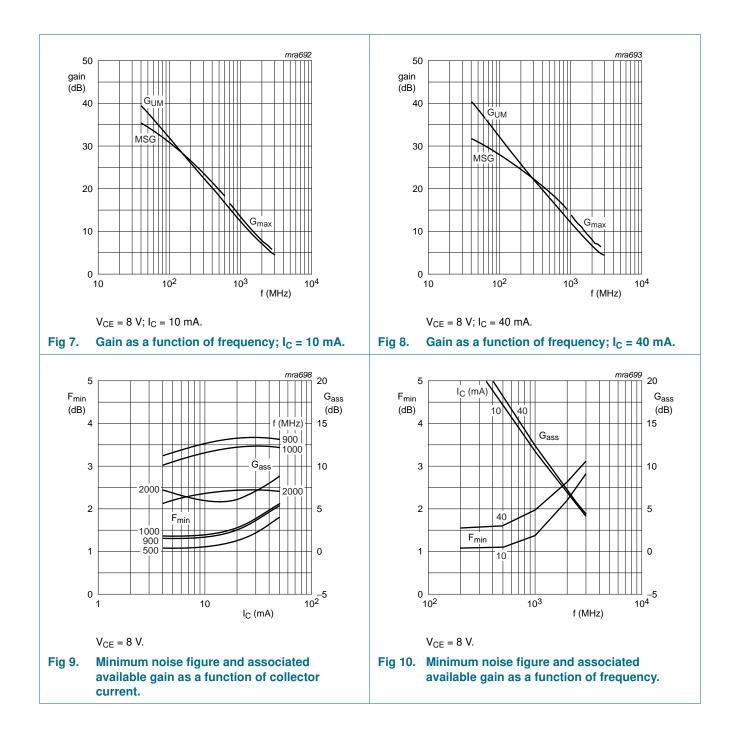
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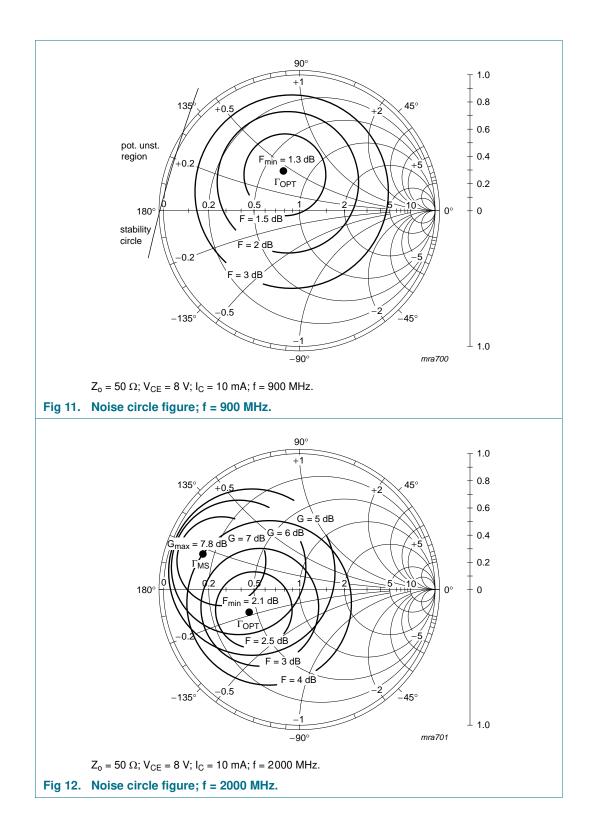
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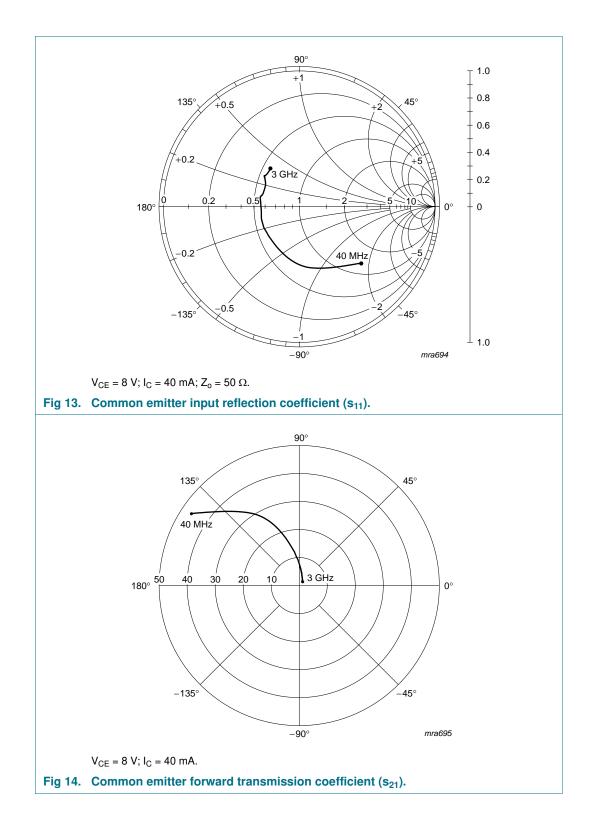
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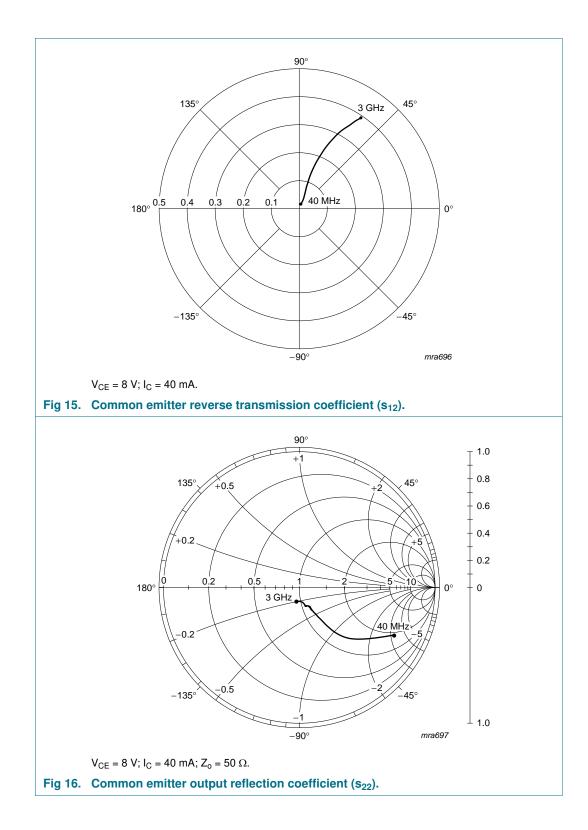
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## 8. Package outline

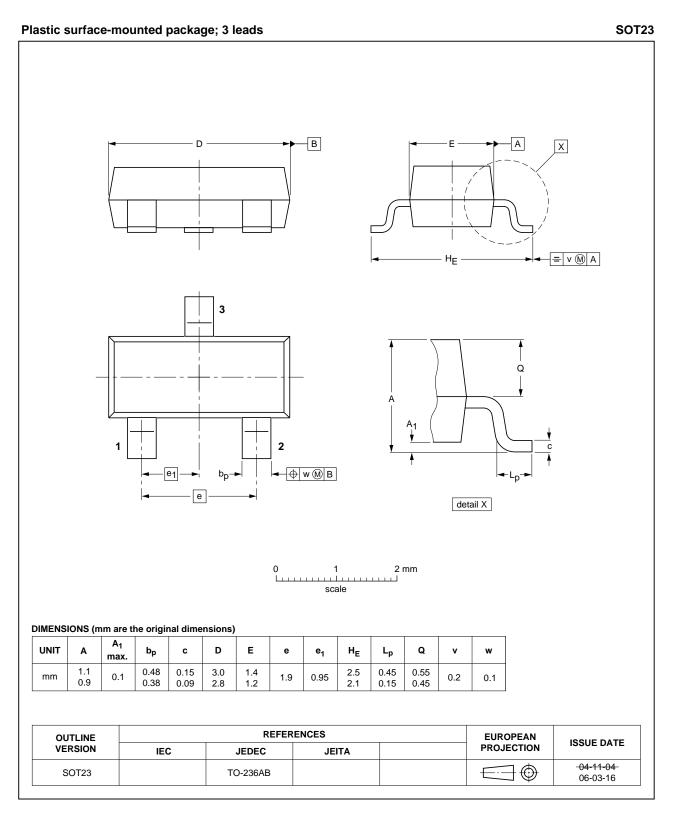


Fig 17. Package outline SOT23 (T0-236AB).

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## 9. Revision history

Table 8. Revision his	story			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BFR540 v.6	20110913	Product data sheet	-	BFR540 v.5
Modifications:	guidelines o Legal texts	of this data sheet has been of NXP Semiconductors. have been adapted to the n utline drawings have been up	ew company name whe	ere appropriate.
BFR540 v.5 (9397 750 13398)	20040901	Product data sheet	-	BFR540 v.4
BFR540 v.4 (9397 750 07062)	20000530	Product specification	-	BFR540 v.3
BFR540 v.3 (9397 750 06338)	19990823	Product specification	-	BFR540_CNV v.2
BFR540 CNV v.2	19971204	Product specification	-	-

## **10. Legal information**

#### 10.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Date of release: 13 September 2011 Document identifier: BFR540